

AGENDA

- Introduction of Renesas Capacitive Touch IP
- RA2L1/RA2E1 Touch Solutions
- Software and tools

INTRODUCTION OF RENESAS **CAPACITIVE TOUCH IP**

IN THE BEGINNING

We have released MCUs for capacitive touch key solutions.



1st Generation Capacitance Sensor IP installed MCU (From 2008 R8C-33T...)

Use OMRON licensed measurement methods.

Supports touch button application only.

2nd Generation Capacitance Sensor IP installed MCU (From 2014 RX113...)

Renesas original measurement method.

High noise immunity.

Mutual capacitance method support

3rd Generation Capacitance Sensor IP installed MCU (From 2019 RA2L1 ...)

RENESAS TOUCH LINE-UP

TOUCH DEVICES











Next devices with new Touch IP coming soon



RL78/G2x



- Self/Mutual technology
- IEC61000 4-3/4-6 Level 3 High sensitivity & High Noise Immunity
- Tools and Drivers VDE Certification in progress Class B





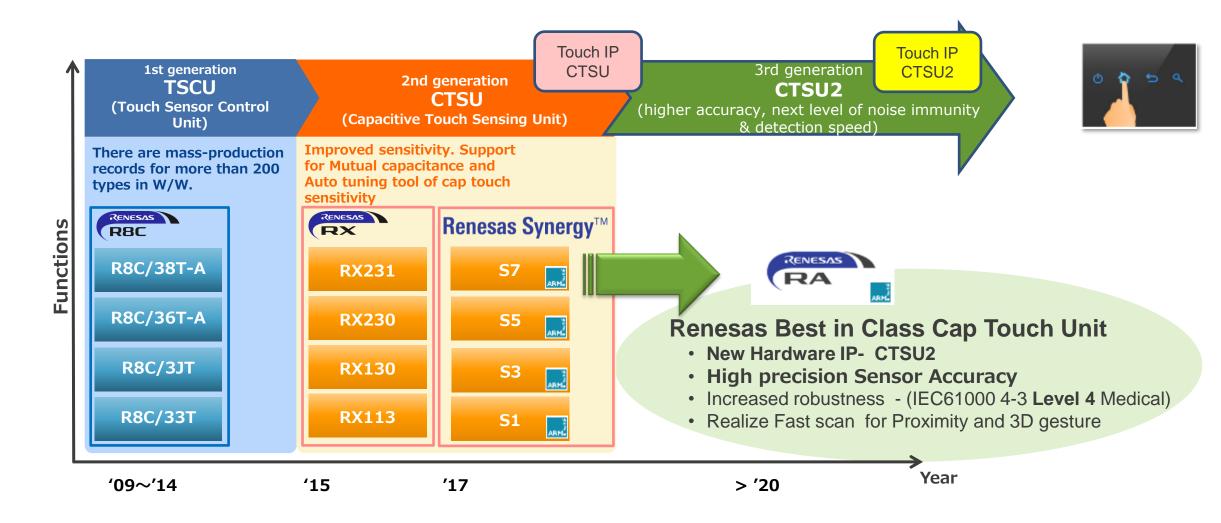


Cooperation proposals:

- Share our experience concerning the touch solutions
- Evaluate the new features embedded in RA2 product line

CAPACITIVE TOUCH SENSOR

IMPROVE TOUCH-KEY SENSOR WHICH HAS A TRACK RECORD ENOUGH



KEYS FEATURES



- Supports Switch, Wheel, Slider and Proximity
- Autonomous operation to enable ultra-low power touch detection
- Support self and mutual-capacitance detection methods
- Hardware-assisted sensing/scanning



High sensitivity

- Sensing of thick acrylic material, wooden material and wear the glove
- Realizing 300mm-proximity sensing



High Noise Immunity

- Enhance water resistance (Mutual)
- Implementing noise-counter measures in hardware saves significant number of CPU cycles
- Passed the IEC61000 4-3/4-6 Level 3

MEASUREMENT PRINCIPLE

TSn

Floating

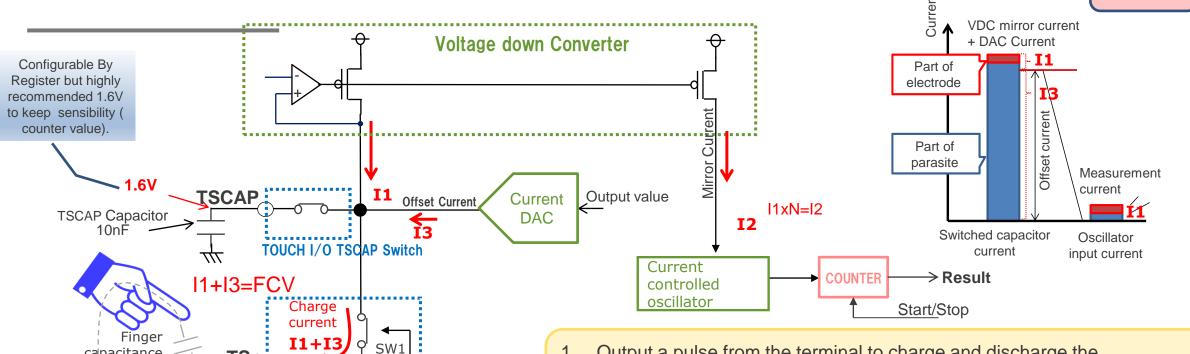
capacitance

Discharge

current

TOUCH I/O Buffer

SW₂



Drive

pulse

- Output a pulse from the terminal to charge and discharge the capacitance (switched capacitor)
- Charge and discharge current is supplied from Current DAC and VDC
- The mirror current of the current supplied from VDC is input to the current control oscillator.
- The output of the oscillator is counted for a fixed time. The microprocessor detects the change in capacitance from the change in count result.

This method integrates. Sensitivity is improved enough to increase the amount of time and number of times.

Touch IP **CTSU**

capacitance

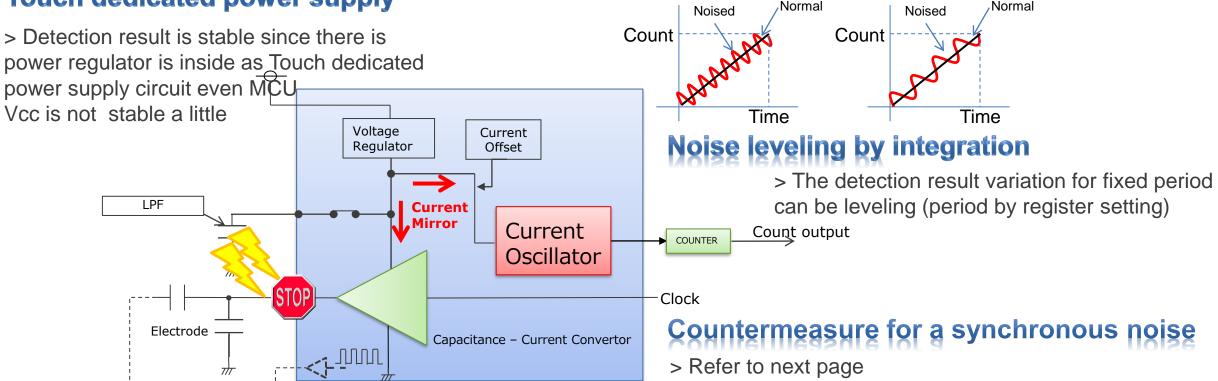
Z/Z

Electrode

NOISE IMMUNITY PRINCIPE



Touch dedicated power supply



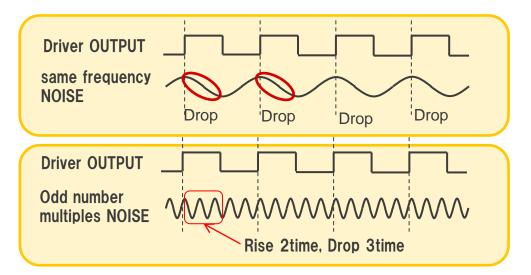
Low - impedance input

> Input terminal is connected SCF (Switched Capacitor Filter) and it has low-impedance and it is hard for the noise to come inside since it always connected Power or GND.

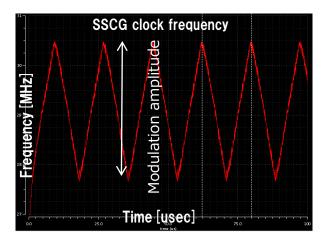
NOISE IMMUNITY PRINCIPLE

Touch IP CTSU

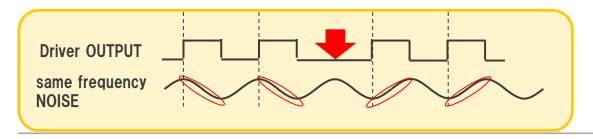
Switched capacitor clock synchronization noise measures Influence occurs for a charge & discharge current the noise that synchronized in a switching period.

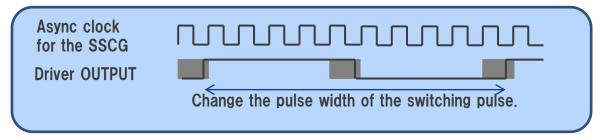


High frequency noise measures The switching pulse is sampled by the SSCG clock to change the pulse width.

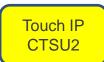


Randomly invert the phase to cancel out the effect.





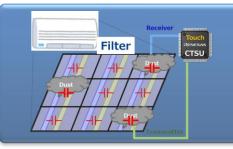
NEW GENERATION CAP TOUCH SENSOR: CTSU2





Upgrade Hardware Noise Immunity Higher conductive & radiative noise immunity

Support IEC61000 4-x Level 4 (30V/m)



Improve Sensor Accuracy

Support Precision Positioning Sensor, High accuracy 3D gesture Sensor and etc.



Fast scanning & Slow Sampling

Support Screen Scan with Multi fingers Detection & Supper Low Emission 3D gesture with 2 fingers detection



Water flow/Level



Paper thickness sensor



Noise sensitive

device



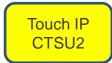
3D gesture with Touch screen with multi fingers Without screen IC______2 fingers detection







NEW FEATURES



1. Panel electrode support

Speed up mutual capacitance measurement with newly developed analog IP.
Parallel measurement for multiple installations. The new macro is CFC.

2. High noise immunity

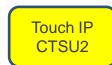
- Active shield support.
- Majority selection by triple frequency measurement.
 IEC61000-4-6 level3 conductive (Support for customer over spec test.)
 IEC61000-4-3 level4 radiative (30v/m)

3. Accuracy improvement and self-correction function

- Correct variations due to manufacturing factors between MCUs.
- Temperature correction is possible.
- ➤ IP self-test is possible. Contributes to functional safety.(IEC60730)

4. Function addition

Small current change measurement function.



Multi Frequency Scan

To avoid synchronous noise affection

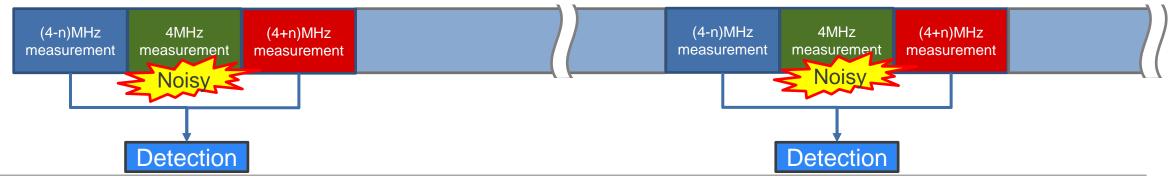
Current method (CTSU)

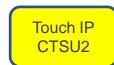
Fixed 1 kind of drive frequency to measure. So there is some affection from synchronous noise all the time.



NEW method (CTSU2)

3 kinds of different frequencies can interpolate the result which includes noise affection.

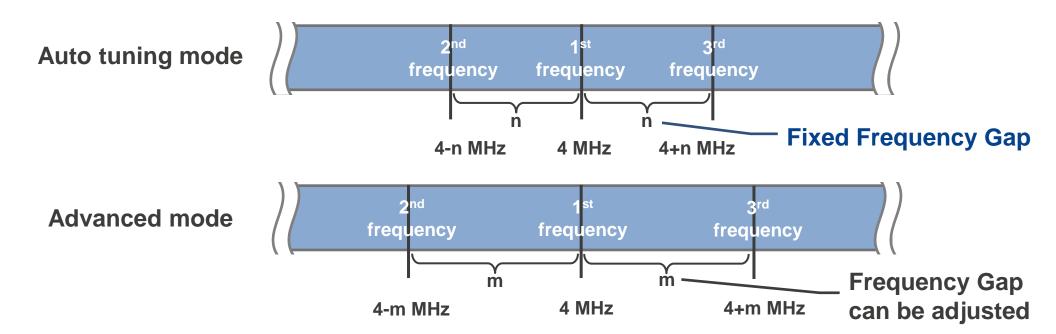


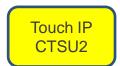


Multi Frequency Scan

To avoid synchronous noise affection

1st Frequency is same as Sensor Drive Pulse as a base frequency 2nd Frequency and 3rd Frequency can be adjusted by setting Frequency gap setting.



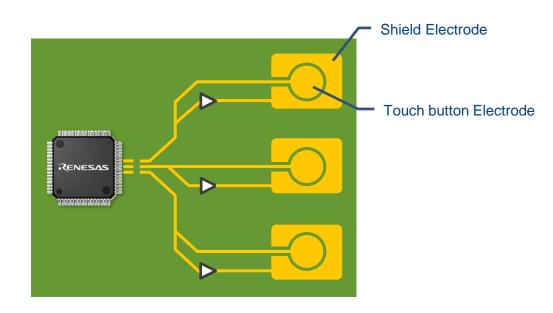


Shield electrode support

CTSU2 supports Shield electrode output in Self capacitance method.

Current method (CTSU)

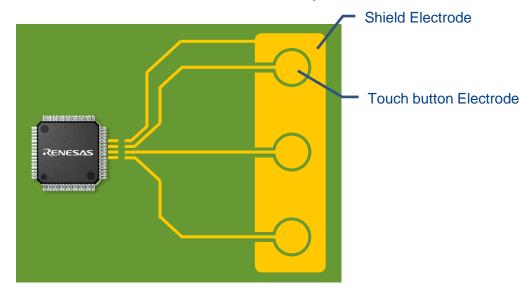
1 electrode Pad requires 1 shield electrode pattern. Each shield electrode requires a current driver.

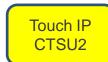


New method (CTSU2)

Several electrode pad can share 1 common shield electrode pattern.

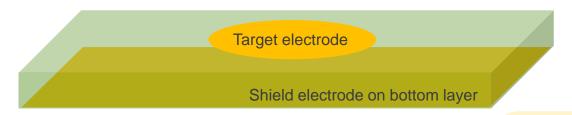
Shield electrode can be driven directly.





Shield electrode support

Shield electrode on bottom layer reduces a parasitic capacitance and a noise affection from bottom direction.

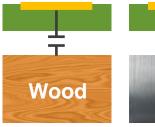


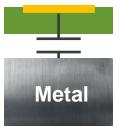
Nothing layouts at the bottom.

Easy to affect from bottom direction.

Parasitic capacitance will change when the condition is changed at the bottom.

Noise will come to electrode directly.

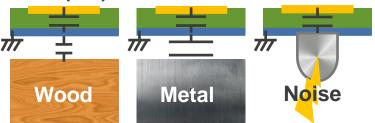






GND pattern at the bottom

Noise from bottom direction can be shielded by GND pattern. However GND pattern is too close to the electrode so parasitic capacitance is got bigger and sensitivity may be reduced.



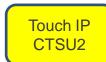
Shield electrode at the bottom

Noise from bottom direction can be shielded by Shield electrode. And parasitic capacitance can be reduced by Shield electrode.



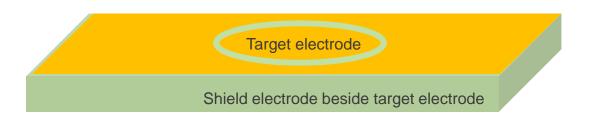






Shield electrode support

Shield electrode beside of target electrode reduces a noise affection and malfunction by the bridge of water drop.



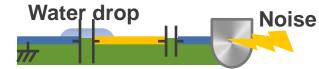
Nothing layouts beside

There is small additional capacitance in case of the bridge by the small water drop. However there is no guard pattern so easy to affect from the noise.



GND pattern layouts decide

GND pattern can be reduced noise affection from the side direction. However the water drop bridge may cause malfunction since capacitance with water drop bridge between electrode and GND is bigger.

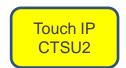


Shield electrode layouts beside

Shield electrode can be reduced noise affection from the side direction. And additional capacitance by the water drop bride is smaller with Shield electrode and it can be reduced the risk of malfunction.



SENSOR ACURACY IMPROVEMENT ON CTSU2



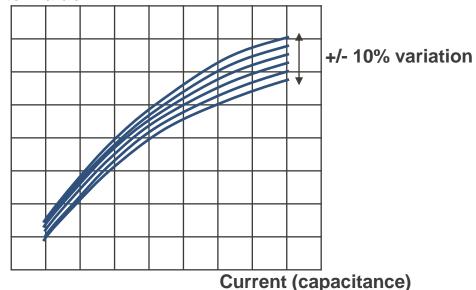
Sensor accuracy is up by improving ICO circuits

Adapt to the application which is required more accuracy such as high precision sensing use.

Current circuit (CTSU)

Current-Counter value variation of temperature drift is +/-10%

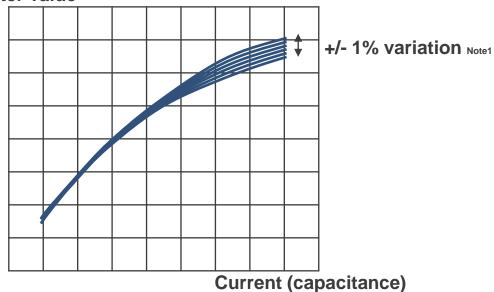
Counter value



New circuit (CTSU2)

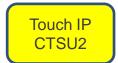
Current-Counter value variation of temperature drift is +/-1%

Counter value



Note1: Target specification

SUPPORT HIGH SPEED SCANNING ON CTSU2



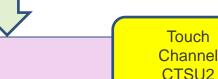
High speed scanning by CFC(Capacitance Frequency Conversion) is ready.

Parallel scanning (up to 20ch detection at the same time) can contribute for high speed scanning.

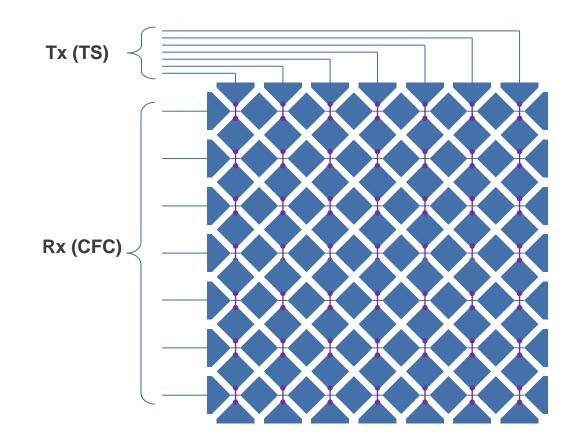
Current method (CTSU)

Touch channel CTSU

- Sequential scanning on Mutual matrix
- 7x7 Matrix takes 49 scanning time.



- CFC terminal can support parallel scanning (Max 20 ch scanning at the same time)
- > 7x7 Matrix takes 7 scanning time



BOM COST REDUCTION

cap touch BOM cost reduction (external components) per cap touch pin

EXTERNAL COMPONENT:

Touch Channel CTSU

- >TSCAP 10nF capacitor
- ➤ ICO tolerance/Temperature drift 68 Ohm resistor 51 Ohm resistor 100 Ohm resistor.
- Each cap touch pin: 560 Ohm resistor



EXTERNAL COMPONENT

Touch Channel CTSU2

- TSCAP : 10nF capacitor
- ➤ Temperature drift correction 10k ohm resistor
- Each cap touch pin: 560 Ohm resistor

RA2L1/RA2E1 TOUCH SOLUTIONS

RENESAS RA FAMILY OF ARM® CORTEX®-M CORES



RA2 Cortex®-M23 48MHz **RA4**Cortex®-M4 & M33
48 ~ 100MHz

RA6Cortex®-M4 & M33
100 ~ 200MHz

Arm Cortex®-M4 / M23 / M33

Package Line-Up LQFP, QFN, BGA, LGA, WLCSP 25 to 176 pins

Integrated secure element functionality with Secure Engine MPU, and TrustZone®

Renesas Heritage of 32-Bit MCU Leadership

Integrated Memory

Flash: 32kB ~ 2MB SRAM: 16kB ~ 640kB DataFlash, StandbyRAM

Rich connectivity
USB FS & HS, CAN FD,
Ethernet, LCD controller

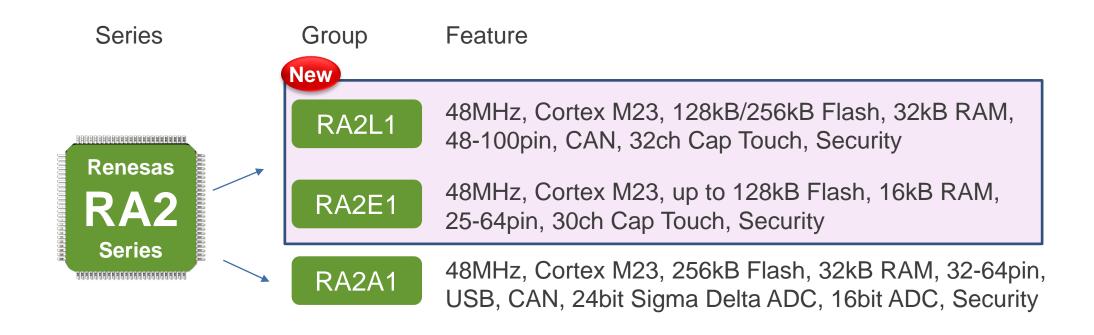
Flexible Software Package
HAL driver and stack

configuration tools, FreeRTOS and partner ecosystem

Scalability

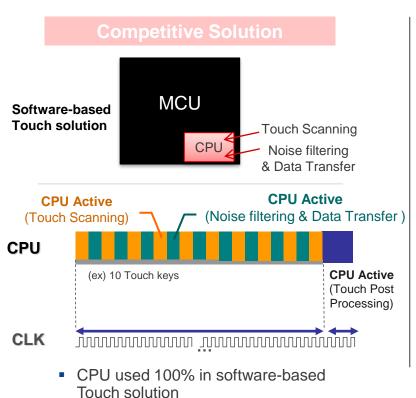
Pin-to-pin & peripheral function, performance 48MHz~200MHz & beyond

RENESAS RA2 SERIES - GROUP OVERVIEW



RA – SOLUTION ADVANTAGES

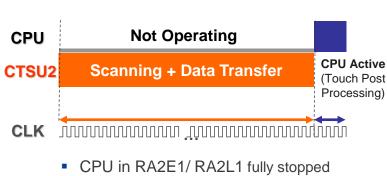
Single chip solutions for system and touch functions



Renesas Solution RA2E1/ RA2L1 CTSU2 CPU

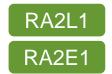
Renesas Patented hardware peripheral (CTSU2) Hardware-assisted sensing/scanning

- Support self and mutual-capacitance detection methods
- Implementing noise-counter measures in hardware saves significant number of CPU cycles
- Autonomous operation to enable ultra-low power touch detection
- Quick reaction by parallel scanning (@ Mutual mode)



Less than 15% CPU usage

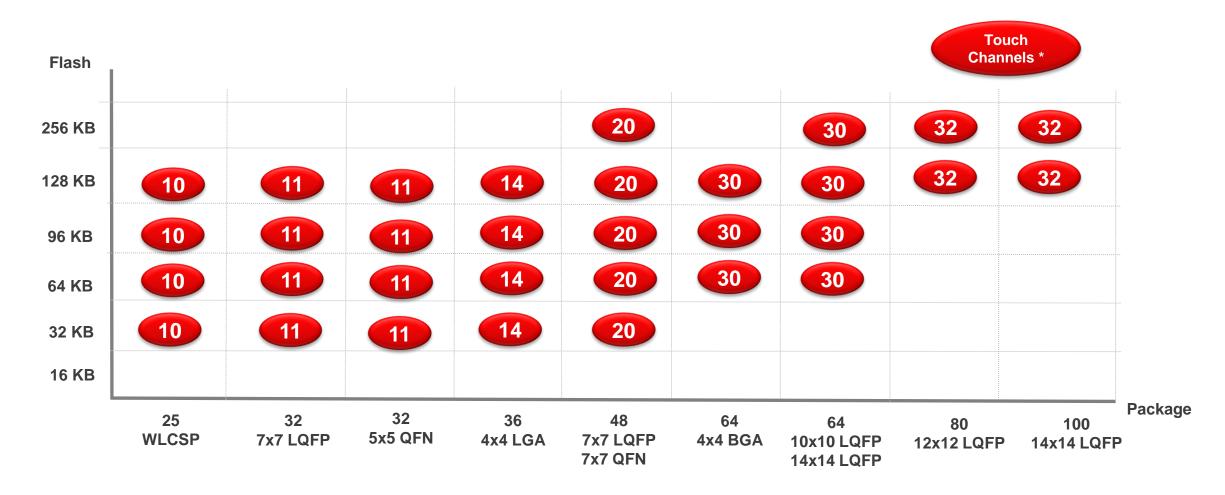
	RA2E1/RA2L1 CTSU2	
Technology	Self, Mutual mode	
Proximity	100mm+ *	
Overlay Thickness (Max.)	10mm (Acrylic) *	
Radiated Noise (IEC61000-4-3)	Level 4 (30V/m) Medical *	
Conducted Noise (IEC61000-4-6) Class B	Level 3 (10V) *	
Inherent Water "Resistance"	Yes (Self/Mutual mode)	
Matrix Configuration Support	Yes (Mutual mode)	
Auto-tuning	Yes	
# of Touch Channels	32 max. * System dependent	



CTSU COMPARISON

Features	CTSU	CTSU2	Advantage
Scan Time (self/1 electrode)	≈ 600 us	Less than 200 us	Better reactivity
Parallel Electrode Scan	Not supported	Implemented in HW(CFC/ mutual)	Improve Scan Time in Mutual design.
Temperature Drift	10 %	Only 1 %	Better noise immunity Improve accuracy
Multi-freq. scan	Only by software	Done by HW	Better noise immunity Improve scan time
Shield Electrode	Not supported	Implemented in HW	Better noise immunity Reduce Parasitic cap
External Components	Min 3 external components	Min 1 external components	Cost
Available in	RX, RA, Synergy	RA2L1 RA2E1	

RA2L1/RA2E1 CAPACITIVE TOUCH LINE-UP



^{* 1} Touch channel = 1 key (no matrix configuration)

RA2L1/RA2E1 USAGE EXAMPLE: APPLIANCE USER INTERFACE

- Major customer in Home Appliance market
- Cap. Touch platform for generic U/I
 - System cost reduction
 - Reliability

- Ease of cleaning
- Water proof
- Navigation



- Customer requests to get the design knowhow in-house.
- Less CPU usage for touch detection
- A full reference design is requested
- Competitors:1. MCU with Software touch solution / 2. MCU + Touch sensor IC



- RA2L1/RA2E1 propose as system control MCU with hardware-assisted touch sensing
- Perform and pass all tests as requested
- Achieve below 15% of CPU usage for touch detection
- BoM costs reduce thanks to Single-chip solution

QUICK AND EFFECTIVE TOOL FOR CAP TOUCH



RA2 RENESAS OFFERS CAPACITIVE TOUCH SOLUTION

Capacitive touch panel development support environment

HARDWARE RA2L1/ RA2E1 (CTSU2 support)



Samples => Now

Quick and Effective Tool



Auto-tuning Tool to configure parameters and monitor the signals. Automatic code creation



SOFTWARE MIDDLEWARE & HAL DRIVER



Open source Low/middle level drivers

KIT Evaluation board RSSK RA2L1





EASY TO DEVELOP FIRMWARE SOFTWARE DRIVERS

TOUCH middleware (rm_touch) and CTSU HAL driver (r_ctsu) provides API to control the CTSU peripheral.

These links with QE for Capacitive Touch [RA].

Capacitance measurements at various settings are possible by editing the configuration using our auto-tuning tools.

rm_touch and r_ctsu are included in Firmware Software package =FSP.

Therefore, these are developed according to the FSP architecture.

Based on RX FIT, but with major changes including API.

CTSU

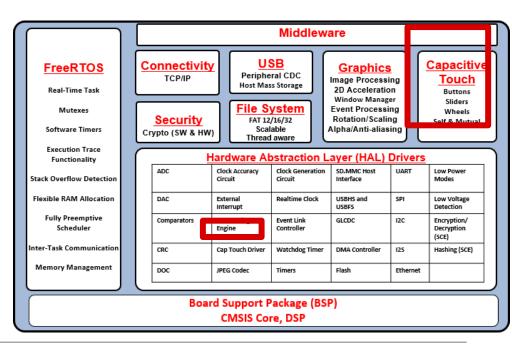
RA2A1, RA4M1, RA6M1, RA6M2, RA6M3, RA4W1

RA6M4/M5, RA4M2/M3

CTSU2

RA2L1, RA2E1

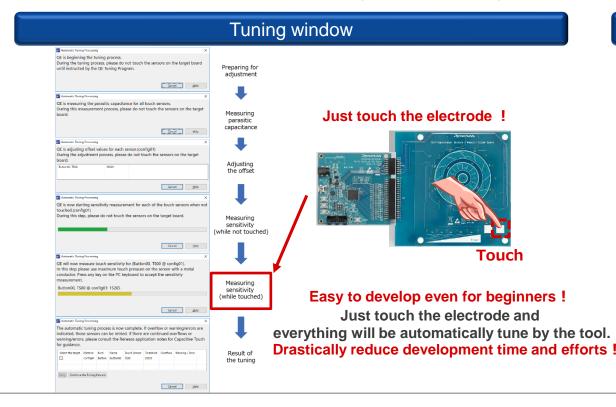


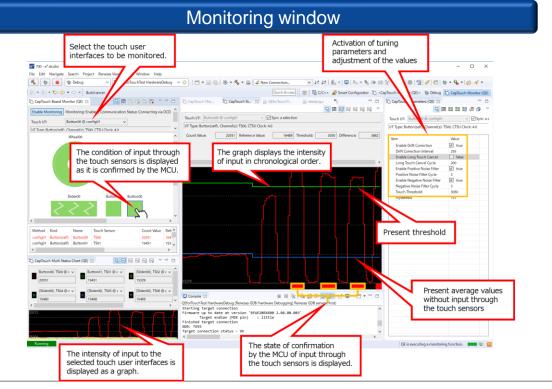




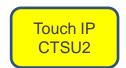


- **QUICK AND EFFECTIVE TOOL: QE**
 - Develop touch I/F with easy-to-operate GUI even for beginners Touch sensor tuning and monitoring with easy- to-operate GUI by just following the instructions
 - Automatic tuning touch sensor sensibility Adjust offset/sensibility via tuning just by following the instructions





SERIAL COMMUNICATION SUPPORT



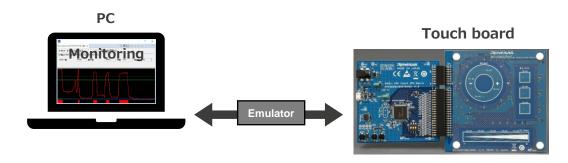
Serial communication support for QE for Capacitive Touch[RA]

Serial communication is useful for monitoring / fine tuning stage after project creation.

User can use not Emulator but USB cable to communicate between QE and touch board.

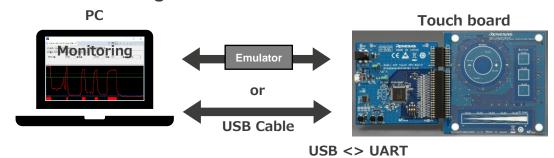
Current QE for Capacitive Touch

User always need to use Emulator connection



NEW QE for Capacitive Touch (In development)

User can select Emulator I/F or Serial communication for Monitoring



CPK-RA2L1 AND CPK-RA2E1

1. Start MCU and Cap-touch evaluation immediately

- On board J-Link debugger to start development with all supported IDEs, e2studio, Keil/MDK and IAR embedded workshop.
- ➤ 3 touch button available, start captouch development workflow with no additional hardware needed.

2. Rich Expansion Option

- > Expansion connector same as EK board.
- Arduino interface
- > 2 PMOD + 1 Grove IIC
- Debug-in and Debug out

3. Support full operation voltage range of RA2

- Debug USB power can support 3.3V or 5V operation.
- With external power supply, can work from 3.0V ~5.5V
- With level shifter board connected, can support 1.6V~3.0V operation.



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